THERMAL DATA

	Thermal Resistance Junction-ambient	Max	3.12	°C/W	
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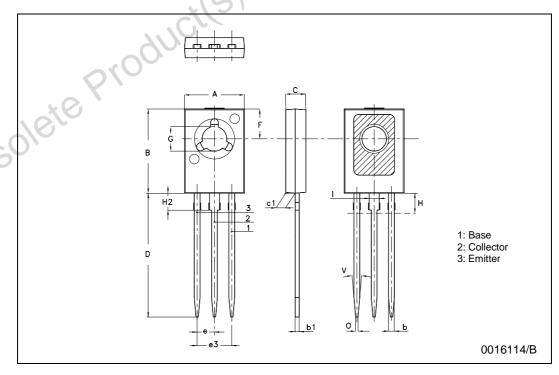
ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

$ \begin{array}{c c} & \text{Current (I}_{E} = 0) \\ \hline \\ I_{EBO} & \text{Emitter Cut-off Current} \\ & (I_{C} = 0) \end{array} \begin{array}{c} V_{EB} = 4 \text{ V} \\ \hline \\ \end{array} $	Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Uni
$ \begin{array}{c c} & (I_C=0) \\ \hline V_{CEO(sus)^*} & Collector\text{-Emitter} \\ Sustaining \ Voltage \\ (I_B=0) \\ \hline \end{array} \begin{array}{c c} I_C=0.1 \ A \\ \hline \end{array} \begin{array}{c} 40 \\ \hline \end{array} \begin{array}{c} 1 \\ \hline$	I _{CBO}		V _{CB} = 40 V			100	μА
Sustaining Voltage (I _B = 0)	I _{EBO}		V _{EB} = 4 V			100	μΑ
h_FE DC Current Gain $I_C = 1 \text{ A}$ $V_{CE} = 1 \text{ V}$ 40 Pulsed: Pulse duration = $300\mu\text{s}$, duty cycle $\leq 1.5\%$, ,	Sustaining Voltage (I _B = 0)					V
* Pulsed: Pulse duration = 300µs, duty cycle ≤ 1.5%	h _{FE}	DC Current Gain	I _C = 1 A V _{CE} = 1 V	40			,
solete Proot				5			
		41)	cile) Obsoli				

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SOT-32 (TO-126) MECHANICAL DATA

DIM.	mm		inch			
DIIVI.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	7.4		7.8	0.291		0.307
В	10.5		10.8	0.413		0.425
b	0.7		0.9	0.028		0.035
b1	0.40		0.65	0.015		0.025
С	2.4		2.7	0.094		0.106
c1	1.0		1.3	0.039		0.051
D	15.4		16.0	0.606		0.630
е		2.2			0.087	
e3		4.4			0.173	
F		3.8		× 0	0.150	
G	3		3.2	0.118		0.126
Н			2.54	.0		0.100
H2		2.15	-10	2	0.084	
1		1.27	Uh		0.05	
0		0.3			0.011	
V		10°			10°	



Obsolete Product(s). Obsolete Product(s)

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